

1200 V Gen 4 Power Silicon Carbide Schottky Diode, 20 A



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | |
|---|-------------|--|--|--|--|
| I _F 20 A | | | | | |
| V _R | 1200 V | | | | |
| V _F at I _F at 25 °C, typ. | 1.38 V | | | | |
| T _J max. | 175 °C | | | | |
| I _R at V _R at 175 °C | 260 μΑ | | | | |
| Q _C (V _R = 800 V) | 101 nC | | | | |
| Package | TO-220AC 2L | | | | |
| Circuit configuration | Single | | | | |

FEATURES

Positive V_F temperature coefficient for easy paralleling



HALOGEN

Virtually no recovery tail and no switching losses

• Temperature invariant switching behavior

• 175 °C maximum operating junction temperature

Ire FREE

• Meets JESD 201 class 1A whisker test

- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 1200 V Schottky diode, designed for high performance and ruggedness.

Optimized for extreme high-speed hard switching across a wide temperature range. This SiC diode is ideal for demanding applications such as high efficiency PFC diodes and ultra-high frequency output rectifiers in AC/DC and DC/DC converters.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise specified) | | | | | | |
|--|--|--|-------------|------------------|--|--|
| PARAMETER SYMBOL TEST COND | | TEST CONDITIONS | VALUES | UNITS | | |
| Peak repetitive reverse voltage | V_{RRM} | | 1200 | V | | |
| Continuous forward or mont | I _F ⁽¹⁾ | T _C = 145 °C (DC) | 20 | Α | | |
| Continuous forward current | I _F ⁽²⁾ | T _C = 129 °C (DC) | 20 | Α | | |
| DC blocking voltage | V_{DC} | | 1200 | V | | |
| Repetitive peak forward current | I _{FRM} | T_C = 25 °C, f = 50 Hz, square wave, DC = 25 % | 69 | Α | | |
| Non-venetitive needs formered according to | I _{FSM} | $T_C = 25$ °C, $t_p = 10$ ms, half sine wave | 116 | | | |
| Non-repetitive peak forward surge current | | $T_C = 110$ °C, $t_p = 10$ ms, half sine wave | 90 | Α | | |
| | P _{tot} (1) | T _C = 25 °C | 125 | | | |
| Davier dissination | | T _C = 110 °C | 54 | W | | |
| Power dissipation | P _{tot} (2) | T _C = 25 °C | 187 | 14/ | | |
| | | T _C = 110 °C | 81 | W | | |
| l²t value | ∫i ² dt | T _C = 25 °C | 67 | A ² s | | |
| i-i value | | T _C = 110 °C | 40 | A ^z S | | |
| Operating junction and storage temperatures | T _J ⁽³⁾ , T _{Stg} | | -55 to +175 | °C | | |

Notes

- $^{(1)}$ Based on typical R_{th}
- (2) Based on maximum Rth
- (3) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|----------------|--|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| | | I _F = 20 A | - | 1.38 | 1.6 | | |
| Forward voltage | V _F | I _F = 20 A, T _J = 150 °C | - | 1.77 | 2.2 | V | |
| | | I _F = 20 A, T _J = 175 °C | - | 1.9 | - | | |
| | I _R | V _R = V _R rated | - | 9 | 150 | μА | |
| Reverse leakage current | | V _R = V _R rated, T _J = 150 °C | - | 120 | 800 | | |
| | | V _R = V _R rated, T _J = 175 °C | - | 260 | - | | |
| Total capacitance | С | V _R = 1 V, f = 1 MHz | - | 1160 | - | nE | |
| | | V _R = 800 V, f = 1 MHz | - | 69 | - | pF | |
| Total capacitive charge | Q_{C} | V _R = 800 V, f = 1 MHz | - | 101 | - | nC | |

| THERMAL - MECHANICAL SPECIFICATIONS (T _A = 25 °C unless otherwise specified) | | | | | | | |
|---|-------------------|--|---|-----|-----|------|--|
| PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS | | | | | | | |
| Thermal resistance, junction-to-case | R _{thJC} | | - | 0.8 | 1.2 | °C/W | |
| Marking device 4C20ET12T | | | | | | | |

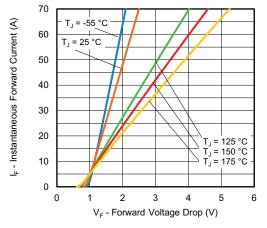


Fig. 1 - Typical Forward Voltage Drop Characteristics

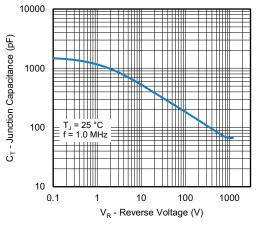


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

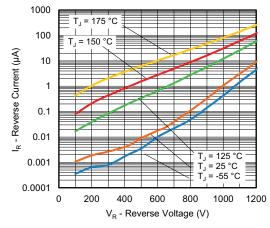


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

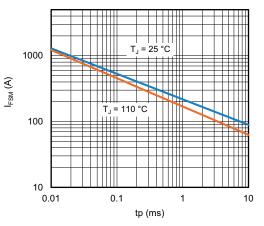


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

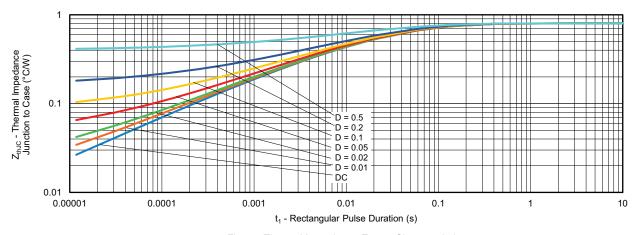


Fig. 5 - Thermal Impedance Z_{thJC} - Characteristics

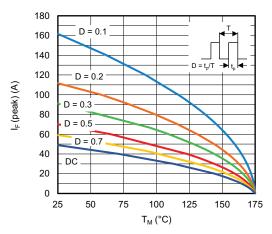


Fig. 6 - Peak Forward Current vs. Maximum Allowable Case Temperature

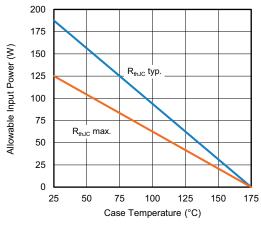


Fig. 7 - Allowable Input Power vs. Case Temperature

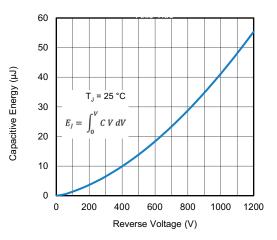


Fig. 8 - Capacitance Energy vs. Reverse Voltage

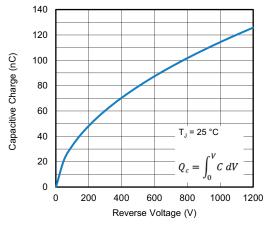
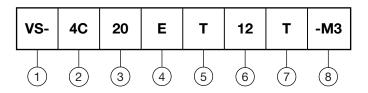


Fig. 9 - Capacitance Change vs. Reverse Voltage



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - 4C = SiC diode, generation 4

3 - Current rating (20 = 20 A)

4 - E = single diode

T = TO-220 package

- Voltage rating: (12 = 1200 V)

7 - T = true 2 pin

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

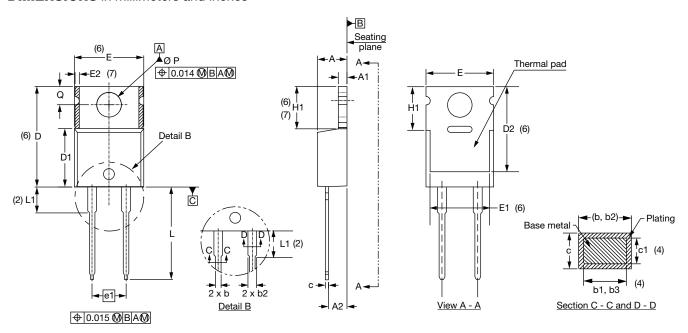
| ORDERING INFORMATION | | | | | | | |
|----------------------|-------------|---------------|--------------------------|--|--|--|--|
| PREFERRED P/N | UNIT WEIGHT | BASE QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-4C20ET12T-M3 | 2 g | 50 / tube | Antistatic plastic tubes | | | | |

| LINKS TO RELATED DOCUMENTS | |
|----------------------------|--------------------------|
| Dimensions | www.vishay.com/doc?96069 |
| Part marking information | www.vishay.com/doc?95391 |



TO-220AC 2L

DIMENSIONS in millimeters and inches



| SYMBOL MILL | | IETERS | INC | NOTES | |
|-------------|-------|--------|-------|-------|-------|
| STINIBUL | MIN. | MAX. | MIN. | MAX. | NOIES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |
| E | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |

| SYMBOL | MILLIN | MILLIMETERS | | INCHES | | |
|----------|--------|-------------|-------|--------|-------|--|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 | |
| E2 | - | 0.76 | - | 0.030 | 7 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | | |
| H1 | 5.84 | 6.86 | 0.230 | 0.270 | 6, 7 | |
| L | 13.52 | 14.02 | 0.532 | 0.552 | | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 | |
| ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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Vishay

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